NSN 5961-01-085-4001

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Inclosure Material:

Metal

Overall Length:

Between 1.103 inches and 1.107 inches

Overall Height:

0.700 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

7.00 milliamperes source cutoff current and 250.00 microamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

90.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

20.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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